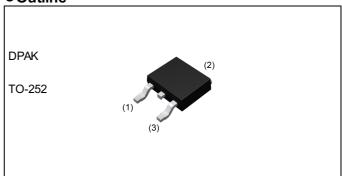
## Nch 60V 80A Power MOSFET

V <sub>DSS</sub>	60V
R <sub>DS(on)</sub> (Max.)	7.5mΩ
I <sub>D</sub>	±80A
P <sub>D</sub>	76W

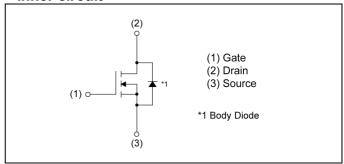
## Outline



### Features

Low on-resistance Pb-free plating;RoHS compliant 100% Avalanche tested AEC-Q101 qualified

## ●Inner circuit



## Application

ADAS/Info./Lighting/Body

## Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	16
	Quantity (pcs)	2500
	Taping code	TL
	Marking	RD3L08DBK

## ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V <sub>DSS</sub>	60	V
Continuous drain current	V <sub>GS</sub> = 10V	I <sub>D</sub> *1	±80	Α
Pulsed drain current	I <sub>DP</sub> *2	±160	Α	
Gate - Source voltage	V <sub>GSS</sub>	±20	V	
Avalanche current, single pulse	I <sub>AS</sub> *3	27	А	
Avalanche energy, single pulse	E <sub>AS</sub> *3	28	mJ	
Power dissipation	P <sub>D</sub> *1	76	W	
Junction temperature	T <sub>j</sub>	175	°C	
Operating junction and storage ter	nperature range	T <sub>stg</sub>	-55 to +175	°C

## ●Thermal resistance

Parameter	Symbol	Values			Linit
		Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	1.97	°C/W

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Doromotor	Symbol Conditions -		Values			Lloit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	akdown $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		60	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I <sub>D</sub> = 1mA referenced to 25°C	-	34	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V	-	-	1	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	1	-	±500	nA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 666 \mu A$	1.0	-	2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 666μA referenced to 25°C	-	-5.0	-	mV/°C	
Static drain - source	D *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 80A	-	5.8	7.5	O	
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 40A	-	8.2	11.5	mΩ	
Gate resistance	$R_G$	f = 1MHz, open drain	1	1.8	-	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 5V, I <sub>D</sub> = 10A	12	-	-	S	

<sup>\*1</sup>  $T_c$ =25°C , Limited only by maximum junction temperature Tj=175°C.

<sup>\*2</sup> Pw ≤10µs , Duty cycle ≤1%

<sup>\*3</sup> L=0.05mH,  $V_{DD}$ =30V,  $R_G$ =25 $\Omega$ , Starting Tj=25 $^{\circ}$ C, See Fig.3-1,3-2

<sup>\*4</sup> Pulsed

# • Electrical characteristics $(T_a = 25^{\circ}C)$

Daramatar	Cymahal	Conditions	Values			Lloit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	1480	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 30V	-	335	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	23	-		
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 30V, V_{GS} = 10V$	1	18	1		
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 10A	1	15	1	no	
Turn - off delay time	$t_{d(off)}^{*4}$	$R_L \simeq 3\Omega$	1	50		ns	
Fall time	t <sub>f</sub> *4	$R_G = 1\Omega$	-	11	-		

## • Gate charge characteristics $(T_a = 25^{\circ}C)$

Daramatar	Cymahal	Conditions		Values			l limit
Parameter	Symbol			Min.	Тур.	Max.	Unit
Total gate charge	otal gate charge $Q_g^{\star 4}$	V <sub>DD</sub> ≃ 30V	V <sub>GS</sub> = 10V	-	22.0	-	
lotal gate charge				-	11.3	-	<b>5</b> C
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 10A	V <sub>GS</sub> = 4.5V	-	3.9	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4			-	3.7	-	

## ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol Conditions		Values			Unit
	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub> *1	T = 25°C	-	-	50	Α
Pulse forward current	I <sub>SP</sub> *2	T <sub>a</sub> = 25°C	-	-	160	Α
Forward voltage	V <sub>SD</sub> *4	$V_{GS} = 0V, I_{S} = 50A$	-	-	1.5	V
Reverse recovery time	t <sub>rr</sub> *4	I <sub>S</sub> = 10A, V <sub>GS</sub> =0V	-	37	-	ns
Reverse recovery charge	Q <sub>rr</sub> *4	di/dt = 100A/μs	-	39	-	nC

Power Dissipation: P<sub>D</sub>/P<sub>Dmax</sub>. [%]

### • Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

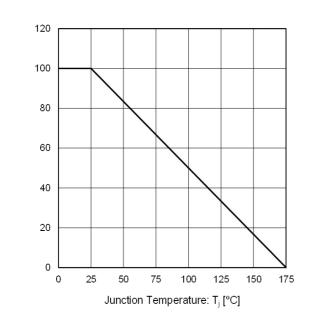
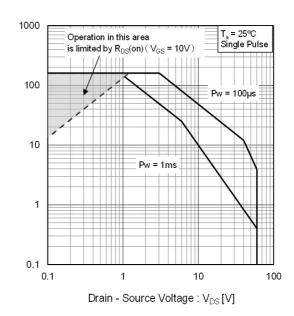


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

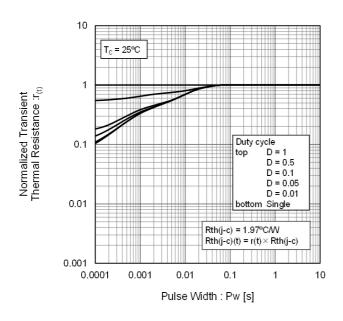
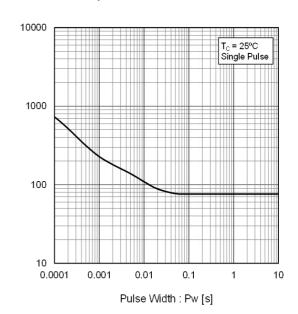


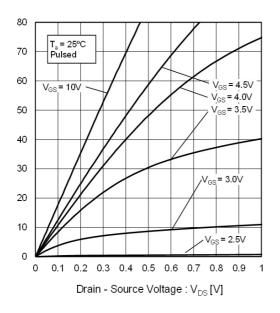
Fig.4 Single Pulse Maximum Power dissipation



Peak Transient Power: P[W]

### • Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



Drain Current : I<sub>D</sub> [A]

Fig.6 Typical Output Characteristics(II)

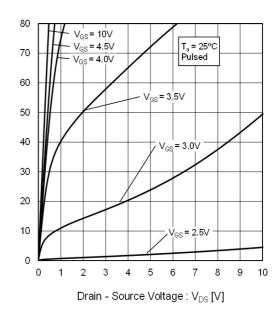
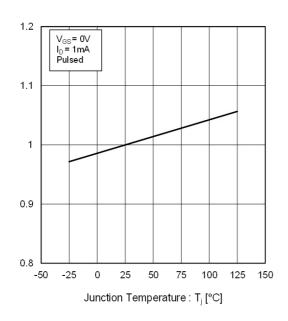


Fig.7 Breakdown Voltage vs.
Junction Temperature



Drain Current : I<sub>D</sub> [A]

Drain Current : I<sub>D</sub> [A]

## • Electrical characteristic curves

Fig.8 Typical Transfer Characteristics

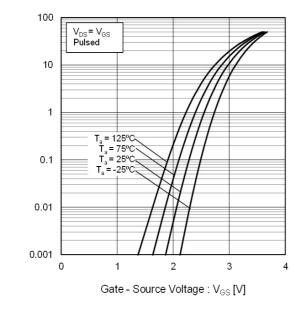


Fig.9 Gate Threshold Voltage vs.
Junction Temperature

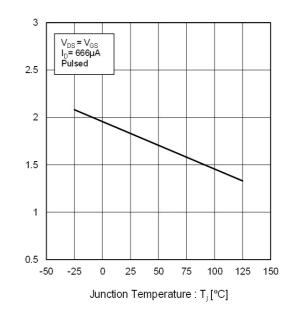
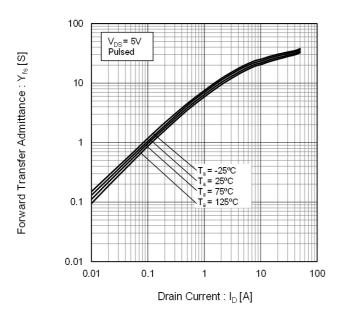


Fig.10 Forward Transfer Admittance vs.
Drain Current



Gate Threshold Voltage :  $V_{GS(th)}$  [V]

Drain Current Dissipation: Ip/Ipmax. [%]

### • Electrical characteristic curves

Fig.11 Drain Current Derating Curve

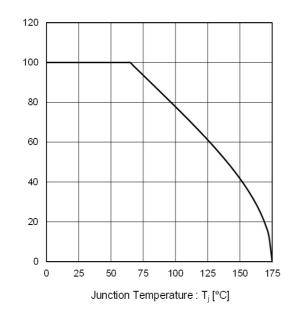
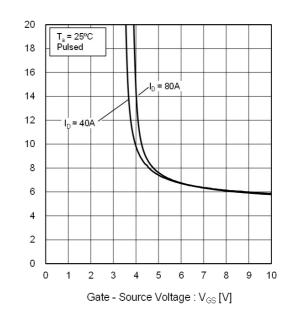
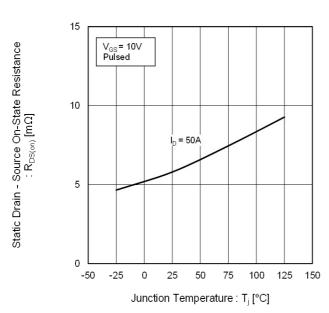


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance :  $R_{\text{DS}(on)}\left[\text{m}\Omega\right]$ 

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



### • Electrical characteristic curves

Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

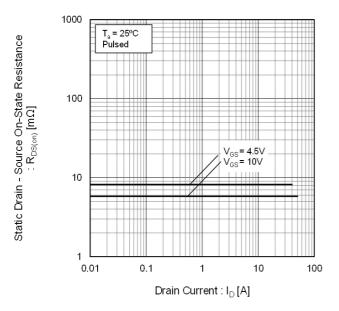
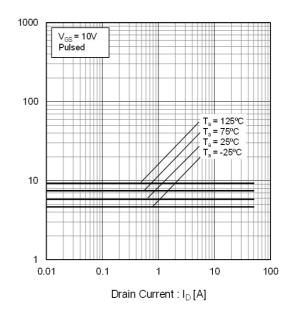
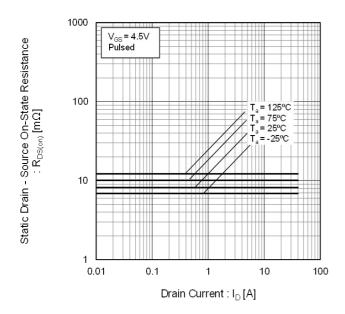


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)



Static Drain - Source On-State Resistance :  $R_{\text{DS}(\text{on})} \left[ \text{m} \Omega \right]$ 

Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)



### • Electrical characteristic curves

Fig.17 Typical Capacitance vs.

Drain - Source Voltage

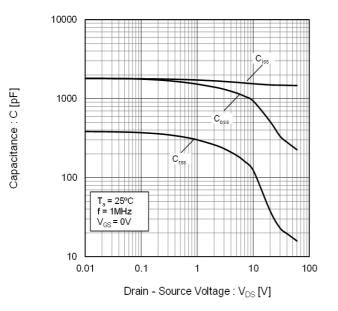


Fig.18 Switching Characteristics

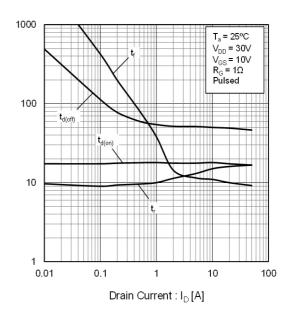


Fig.19 Dynamic Input Characteristics

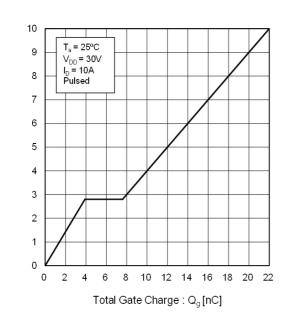
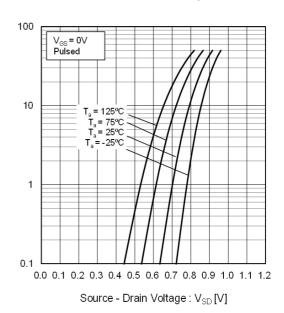


Fig.20 Source Current vs.

Source Drain Voltage



Gate - Source Voltage :  $V_{GS}$  [V]

Source Current : I<sub>S</sub> [A]

Switching Time : t [ns]

## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

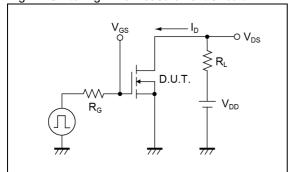


Fig.2-1 Gate Charge Measurement Circuit

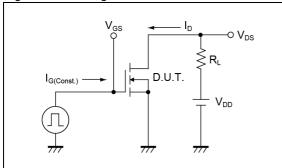


Fig.3-1 Avalanche Measurement Circuit

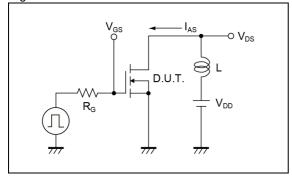


Fig.1-2 Switching Waveforms

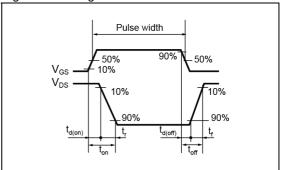


Fig.2-2 Gate Charge Waveform

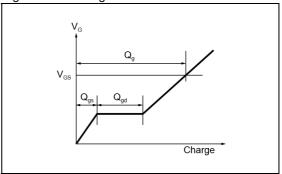
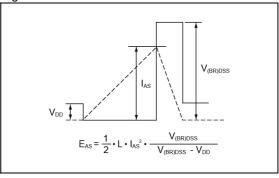
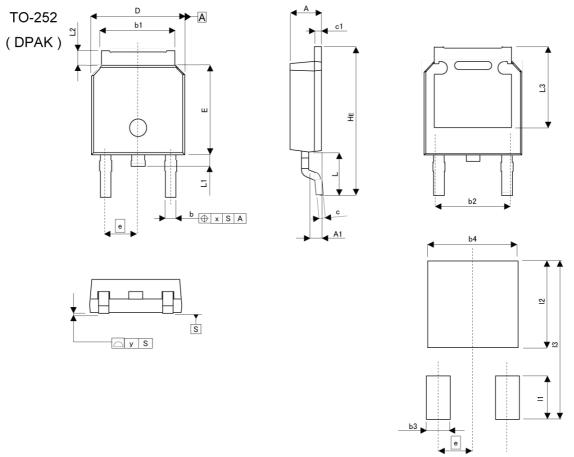


Fig.3-2 Avalanche Waveform



## Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

	N/II IN/IE	TERS	INC	HES
DIM	MIN	MAX	MIN	MAX
		2.30		0.091
A	2.10		0.083	
A1	0.70	1.10	0.028	0.043
b	0.65	0.85	0.026	0.033
b1	5.10	5.40	0.201	0.213
b2	5.	10	0.2	201
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.40	6.80	0.252	0.268
е	2.	30	0.0	91
E	6.00	6.40	0.236	0.252
HE	9.50	10.50	0.374	0.413
L	2.	90	0.1	14
L1	0.70	0.90	0.028	0.035
L2	0.70	1.30	0.028	0.051
L3	5.	30	0.2	209
Х	-	0.25	-	0.010
У	-	0.10	-	0.004

DIM	MILIMETERS		INCHES			
DIIVI	MIN	MAX	MIN	MAX		
b3	o <del>-</del>	1.10	-	0.043		
b4	1-	5.40	-	0.213		
l1	-	2.90	-	0.114		
12	1-	5.50	-	0.217		
13	-	10.50	-	0.413		

Dimension in mm/inches



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(Note1) Medical Equipment Classification of the Specific Applications

ſ	JÁPAN	USA	EU	CHINA
Ī	CLASSⅢ	CL ACCIII	CLASS II b	СГУССШ
ſ	CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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